

IN THE U.S. PATENT AND TRADEMARK OFFICE

COPY

Applicant: HWANG, Lee-Yeun

Application No.:

Group:

Filed: May 24, 2001

Examiner:

For: HIGH VOLTAGE DEVICE HAVING POLYSILICON REGION IN TRENCH AND
FABRICATING METHOD THEREOF

LETTER

Honorable Commissioner of Patents
and Trademarks
Washington, D.C. 20231

May 24, 2001
0630-1177P

Sir:

Under the provisions of 35 USC 119 and 37 CFR 1.55(a), the
applicant hereby claims the right of priority based on the following
application(s):

<u>Country</u>	<u>Application No.</u>	<u>Filed</u>
REPUBLIC OF KOREA	43812/2000	07/28/00

A certified copy of the above-noted application(s) is(are)
attached hereto.

If necessary, the Commissioner is hereby authorized in this,
concurrent, and future replies, to charge payment or credit any
overpayment to Deposit Account No. 02-2448 for any additional fees
required under 37 C.F.R. 1.16 or under 37 C.F.R. 1.17; particularly,
extension of time fees.

Respectfully submitted,

BIRCH, STEWART, KOLASCH & BIRCH, LLP

By:  #37275

GARY D. YACURA

Reg. No. 35,416

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Attachment
(703) 205-8000
/nv

COPY

630-1177
WANG, Lee-Yeun
May 24, 2001
0030-1177P
(703) 205-8000
BSKB, LLD

대한민국 특허청

KOREAN INDUSTRIAL
PROPERTY OFFICE

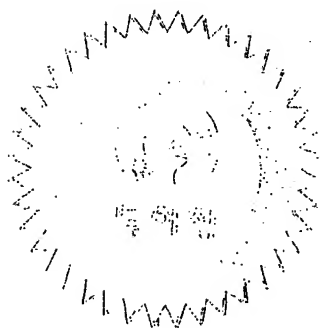
별첨 사본은 아래 출원의 원본과 동일함을 증명함.

This is to certify that the following application annexed hereto
is a true copy from the records of the Korean Industrial
Property Office.

출원번호 : 특허출원 2000년 제 43812 호
Application Number

출원년월일 : 2000년 07월 28일
Date of Application

출원인 : 현대전자산업주식회사
Applicant(s)



2000 년 09 월 02 일

특 허 청

COMMISSIONER

